

#### 2-OUTPUT VERY LOW POWER PCIE GEN 1-2-3-4 CLOCK GENERATOR

9FGV0231

### **Description**

The 9FGV0231 is a 2-output very low-power clock generator for PCle Gen 1, 2, 3 and 4 Common Clocked (CC) applications. The device has 2 output enables for clock management and supports 2 different spread spectrum levels in addition to spread off.

### Recommended Application

PCIe Gen1-4 clock generation for Riser Cards, Storage, Networking, JBOD, Communications, Access Points

### **Output Features**

- 2 0.7V low-power HCSL-compatible (LP-HCSL) DIF pairs
- 1 1.8V LVCMOS REF output w/Wake-On-LAN (WOL) support

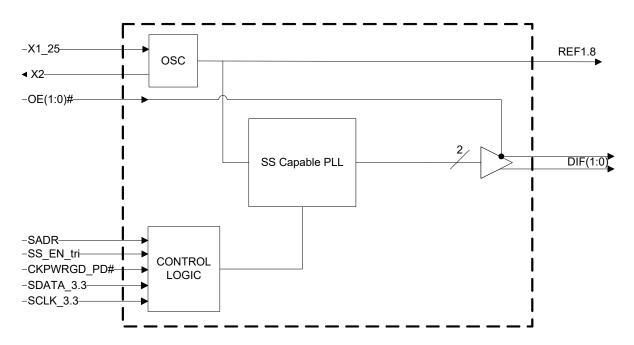
### **Key Specifications**

- DIF cycle-to-cycle jitter <50ps
- DIF output-to-output skew <50ps
- PCIe Gen1-2-3-4 CC-compliant
- REF phase jitter is < 1.5ps RMS

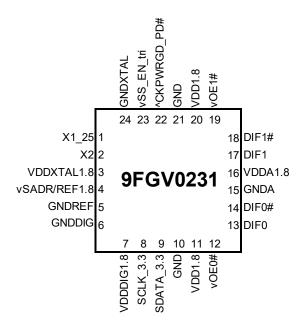
#### Features/Benefits

- 1.8V operation; reduced power consumption
- OE# pins; support DIF power management
- LP-HCSL differential clock outputs; reduced power and board space
- Programmable Slew rate for each output; allows tuning for various line lengths
- Programmable output amplitude; allows tuning for various application environments
- DIF outputs blocked until PLL is locked; clean system start-up
- Selectable 0%, -0.25% or -0.5% spread on DIF outputs; reduces EMI
- External 25MHz crystal; supports tight ppm with 0 ppm synthesis error
- Configuration can be accomplished with strapping pins;
   SMBus interface not required for device control
- 3.3V tolerant SMBus interface works with legacy controllers
- Space saving 4 x 4 mm 24-VFQFPN; minimal board space

### **Block Diagram**



### **Pin Configuration**



#### 24-pin VFQFPN, 4x4 mm, 0.5mm pitch

^ prefix indicates internal 120KOhm pull up resistor v prefix indicates internal 120KOhm pull down resistor

#### **SMBus Address Selection Table**

	SADR	Address	+ Read/Write Bit
State of SADR on first application	0	1101000	x
of CKPWRGD_PD#	1	1101010	х

#### **Power Management Table**

CKPWRGD PD#	SMBus	DI	REF	
CKFWKGD_FD#	OE bit	True O/P	Comp. O/P	INLI
0	Х	Low	Low	Hi-Z <sup>1</sup>
1	1	Running	Running	Running
1	0	Low	Low	Low

<sup>1.</sup> REF is Hi-Z until the 1st assertion of CKPWRGD\_PD# high. After this, when CKPWRG PD# is low, REF is Low.

#### **Power Connections**

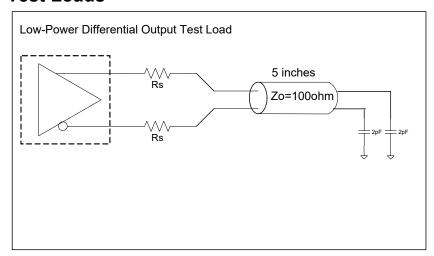
Pin Number		Description
VDD	GND	Description
3	5,24	XTAL, REF
7	6	Digital
11,20	10,21	DIF outputs
16	15	PLL Analog



### **Pin Descriptions**

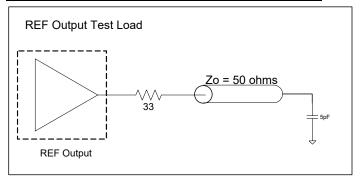
Pin#	Pin Name	Type	Pin Description
1	X1_25	IN	Crystal input, Nominally 25.00MHz.
2	X2	OUT	Crystal output.
3	VDDXTAL1.8	PWR	Power supply for XTAL, nominal 1.8V
4	vSADR/REF1.8	LATCHED I/O	Latch to select SMBus Address/1.8V LVCMOS copy of X1 pin.
5	GNDREF	GND	Ground pin for the REF outputs.
6	GNDDIG	GND	Ground pin for digital circuitry
7	VDDDIG1.8	PWR	1.8V digital power (dirty power)
8	SCLK_3.3	IN	Clock pin of SMBus circuitry, 3.3V tolerant.
9	SDATA_3.3	I/O	Data pin for SMBus circuitry, 3.3V tolerant.
10	GND	GND	Ground pin.
11	VDD1.8	PWR	Power supply, nominal 1.8V
12	vOE0#	IN	Active low input for enabling DIF pair 0. This pin has an internal pull-down.
12	VOE0#	IIN	1 =disable outputs, 0 = enable outputs
13	DIF0	OUT	Differential true clock output
14	DIF0#	OUT	Differential Complementary clock output
15	GNDA	GND	Ground pin for the PLL core.
16	VDDA1.8	PWR	1.8V power for the PLL core.
17	DIF1	OUT	Differential true clock output
18	DIF1#	OUT	Differential Complementary clock output
19	vOE1#	IN	Active low input for enabling DIF pair 1. This pin has an internal pull-down.
19	VOE1#	IIN	1 =disable outputs, 0 = enable outputs
20	VDD1.8	PWR	Power supply, nominal 1.8V
21	GND	GND	Ground pin.
			Input notifies device to sample latched inputs and start up on first high assertion.
22	^CKPWRGD_PD#	IN	Low enters Power Down Mode, subsequent high assertions exit Power Down
			Mode. This pin has internal pull-up resistor.
23	VCC EN tri	LATCHED IN	Latched select input to select spread spectrum amount at initial power up :
23	vSS_EN_tri	LATCHED IN	1 = -0.5% spread, M = -0.25%, 0 = Spread Off
24	GNDXTAL	GND	GND for XTAL

### **Test Loads**

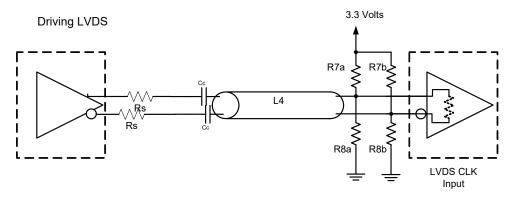


#### **Alternate Differential Output Terminations**

Rs	Zo	Units
33	100	Ohms
27	85	Offilis



### **Alternate Terminations**



#### Driving LVDS inputs with the 9FGV0231

	,		
	Receiver has	Receiver does not	
Component	termination	have termination	Note
R7a, R7b	10K ohm	140 ohm	
R8a, R8b	5.6K ohm	75 ohm	
Сс	0.1 uF	0.1 uF	
Vcm	1.2 volts	1.2 volts	

IDT® 2-OUTPUT VERY LOW POWER PCIE GEN 1-2-3-4 CLOCK GENERATOR

9FGV0231

**JUNE 6, 2019** 

### **Absolute Maximum Ratings**

Stresses above the ratings listed below can cause permanent damage to the 9FGV0231. These ratings, which are standard values for IDT commercially rated parts, are stress ratings only. Functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods can affect product reliability. Electrical parameters are guaranteed only over the recommended operating temperature range.

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
1.8V Supply Voltage	VDDxx	Applies to All VDD pins	-0.5		2.5	V	1,2
Input Voltage	$V_{IN}$		-0.5		$V_{DD}$ +0.3 $V$	V	1, 3
Input High Voltage, SMBus	$V_{IHSMB}$	SMBus clock and data pins			3.6V	V	1
Storage Temperature	Ts		-65		150	°C	1
Junction Temperature	Tj				125	ç	1
Input ESD protection	ESD prot	Human Body Model	2000			V	1

<sup>&</sup>lt;sup>1</sup>Guaranteed by design and characterization, not 100% tested in production.

### **Electrical Characteristics–Current Consumption**

TA = T<sub>COM</sub> or T<sub>IND:</sub> Supply Voltage per VDD of normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Operating Supply Current	I <sub>DDAOP</sub>	VDDA, PLL Mode, All outputs active @100MHz		7	8	mA	1
Operating Supply Current	I <sub>DDOP</sub>	VDD, All outputs active @100MHz		15	8 mA 1 18 mA 1 8 mA 1	1	
Suspend Supply Current	I <sub>DDSUSP</sub>	VDDxxx, PD# = 0, Wake-On-LAN enabled		6	8	mA	1
Powerdown Current	I <sub>DDPD</sub>	PD#=0		0.6	1	mA	1, 2

<sup>&</sup>lt;sup>1</sup>Guaranteed by design and characterization, not 100% tested in production.

### Electrical Characteristics – Output Duty Cycle, Jitter, and Skew Characteristics

TA = T<sub>COM</sub> or T<sub>IND;</sub> Supply Voltage per VDD of normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Duty Cycle	t <sub>DC</sub>	Measured differentially, PLL Mode	45	49.9	55	%	1
Skew, Output to Output	t <sub>sk3</sub>	V <sub>T</sub> = 50%		37	50	ps	1
Jitter, Cycle to cycle	t <sub>jcyc-cyc</sub>	PLL mode		12	50	ps	1,2

<sup>&</sup>lt;sup>1</sup>Guaranteed by design and characterization, not 100% tested in production.

<sup>&</sup>lt;sup>2</sup> Operation under these conditions is neither implied nor guaranteed.

<sup>&</sup>lt;sup>3</sup> Not to exceed 2.5V.

<sup>&</sup>lt;sup>2</sup>Assuming REF is not running in power down state

<sup>&</sup>lt;sup>2</sup> Measured from differential waveform



# **Electrical Characteristics-Input/Supply/Common Parameters-Normal Operating Conditions**

TA = T<sub>COM</sub> or T<sub>IND</sub>: Supply Voltage per VDD of normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
1.8V Supply Voltage	VDD	Supply voltage for core, analog and single-ended LVCMOS outputs	1.7	1.8	1.9	V	1
Ambient Operating	T <sub>COM</sub>	Commercial range	0	25	70	°C	1
Temperature	T <sub>IND</sub>	Industrial range	-40	25	85	°C	1
Input High Voltage	$V_{IH}$	Single-ended inputs, except SMBus	0.75 V <sub>DD</sub>		$V_{DD} + 0.3$	V	1
Input Mid Voltage	$V_{IM}$	Single-ended tri-level inputs ('_tri' suffix, if present)	$0.4~V_{DD}$		0.6 V <sub>DD</sub>	V	1
Input Low Voltage	$V_{IL}$	Single-ended inputs, except SMBus	-0.3		0.25 V <sub>DD</sub>	V	1
Schmitt Trigger Positive Going Threshold Voltage	V <sub>T+</sub>	Single-ended inputs, where indicated	0.4 V <sub>DD</sub>		0.7 V <sub>DD</sub>	V	1
Schmitt Trigger Negative Going Threshold Voltage	V <sub>T-</sub>	Single-ended inputs, where indicated	0.1 V <sub>DD</sub>		0.4 V <sub>DD</sub>	V	1
Hysteresis Voltage	$V_{H}$	$V_{T+}$ - $V_{T-}$	0.1 V <sub>DD</sub>		0.4 V <sub>DD</sub>	V	1
Output High Voltage	$V_{IH}$	Single-ended outputs, except SMBus. $I_{OH}$ = -2mA	V <sub>DD</sub> <b>-</b> 0.45			V	1
Output Low Voltage	$V_{IL}$	Single-ended outputs, except SMBus. $I_{OL}$ = -2mA			0.45	V	1
	I <sub>IN</sub>	Single-ended inputs, $V_{IN}$ = GND, $V_{IN}$ = VDD	-5		5	uA	1
Input Current	I <sub>INP</sub>	$\label{eq:VIN} Single-ended inputs $$V_{IN}=0\ V;$ Inputs with internal pull-up resistors $$V_{IN}=VDD;$ Inputs with internal pull-down resistors$	-20		20	uA	1
Input Frequency	F <sub>in</sub>	XTAL, or X1 input	23	25	27	MHz	1
Pin Inductance	L <sub>pin</sub>				7	nH	1
Capacitance	C <sub>IN</sub>	Logic Inputs, except DIF_IN	1.5		5	pF	1
Сараспансе	C <sub>OUT</sub>	Output pin capacitance			6	pF	1
Clk Stabilization	T <sub>STAB</sub>	From V <sub>DD</sub> Power-Up and after input clock stabilization or de-assertion of PD# to 1st clock		0.6	1.8	ms	1,2
SS Modulation Frequency	f <sub>MOD</sub>	Allowable Frequency (Triangular Modulation)	31	31.6	32	kHz	1
OE# Latency	t <sub>LATOE#</sub>	DIF start after OE# assertion DIF stop after OE# deassertion	1	2	3	clocks	1,3
Tdrive_PD#	t <sub>DRVPD</sub>	DIF output enable after PD# de-assertion			300	us	1,3
Tfall	t <sub>F</sub>	Fall time of single-ended control inputs			5	ns	1,2
Trise	t <sub>R</sub>	Rise time of single-ended control inputs			5	ns	1,2
SMBus Input Low Voltage	V <sub>ILSMB</sub>	$V_{DDSMB}$ = 3.3V, see note 4 for $V_{DDSMB}$ < 3.3V			0.8	V	1,4
SMBus Input High Voltage	V <sub>IHSMB</sub>	$V_{DDSMB}$ = 3.3V, see note 5 for $V_{DDSMB}$ < 3.3V	2.1		3.6	V	1,5
SMBus Output Low Voltage	V <sub>OLSMB</sub>	@ I <sub>PULLUP</sub>			0.4	V	1
SMBus Sink Current	I <sub>PULLUP</sub>	@ V <sub>OL</sub>	4			mA	1
Nominal Bus Voltage	V <sub>DDSMB</sub>		1.7		3.6	V	1
SCLK/SDATA Rise Time	t <sub>RSMB</sub>	(Max VIL - 0.15) to (Min VIH + 0.15)			1000	ns	1
SCLK/SDATA Fall Time	t <sub>FSMB</sub>	(Min VIH + 0.15) to (Max VIL - 0.15)			300	ns	1
SMBus Operating Frequency	f <sub>MAXSMB</sub>	Maximum SMBus operating frequency			400	kHz	1

<sup>&</sup>lt;sup>1</sup> Guaranteed by design and characterization, not 100% tested in production.

 $<sup>^{2}\,\</sup>mbox{Control}$  input must be monotonic from 20% to 80% of input swing.

 $<sup>^3</sup>$  Time from deassertion until outputs are > 200mV.

 $<sup>^{4}</sup>$  For  $V_{DDSMB}$  < 3.3V,  $V_{ILSMB}$  <= 0.35 $V_{DDSMB}$ .

 $<sup>^{5}</sup>$  For  $V_{DDSMB}$  < 3.3V,  $V_{IHSMB}$  >= 0.65 $V_{DDSMB}$ .

### **Electrical Characteristics-DIF 0.7V Low Power HCSL Outputs**

TA = T<sub>COM</sub> or T<sub>IND</sub>; Supply Voltage per VDD of normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Slew rate	Trf	Scope averaging on 3.0V/ns setting	2	3	4	V/ns	1, 2, 3
Siew rate	111	Scope averaging on 2.0V/ns setting	1	2	3	V/ns	1, 2, 3
Slew rate matching	∆Trf	Slew rate matching, Scope averaging on		5	20	%	1,2,4
Voltage High	$V_{HIGH}$	Statistical measurement on single-ended signal using oscilloscope math function. (Scope		793	850	mV	1,8
Voltage Low	$V_{LOW}$	averaging on)	-150	16	150	'''	1
Max Voltage	Vmax	Measurement on single ended signal using		831	1150	mV	1
Min Voltage	Vmin	absolute value. (Scope averaging off)	-300	-95		IIIV	1
Vswing	Vswing	Scope averaging off	300	1555		mV	1,2
Crossing Voltage (abs)	Vcross_abs	Scope averaging off	300	429	550	mV	1,5
Crossing Voltage (var)	∆-Vcross	Scope averaging off		60	140	mV	1,6

<sup>&</sup>lt;sup>1</sup>Guaranteed by design and characterization, not 100% tested in production.  $C_L$  = 2pF with  $R_S$  = 33Ω for Zo = 50Ω (100Ω differential trace impedance).

# Electrical Characteristics–Filtered Phase Jitter Parameters - PCle Common Clocked (CC) Architectures

T<sub>AMB</sub> = over the specified operating range. Supply Voltages per normal operation conditions, See Test Loads for Loading Conditions

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	Specification Limit	UNITS	NOTES
t <sub>jphPCleG1-CC</sub>		PCle Gen 1	21	25	35	86	ps (p-p)	1, 2, 3
		PCIe Gen 2 Low Band 10kHz < f < 1.5MHz (PLL BW of 5-16MHz, 8-16MHz, CDR = 5MHz)	0.9	0.9	1.1	3	ps (rms)	1, 2
<sup>t</sup> jphPCleG2-CC	Phase Jitter, PLL Mode	PCIe Gen 2 High Band 1.5MHz < f < Nyquist (50MHz) (PLL BW of 5-16MHz, 8-16MHz, CDR = 5MHz)	1.5	1.6	1.9	3.1	ps (rms)	1, 2
t <sub>jphPCleG3-CC</sub>		PCIe Gen 3 (PLL BW of 2-4MHz, 2-5MHz, CDR = 10MHz)	0.3	0.37	0.44	1	ps (rms)	1, 2
t <sub>jphPCleG4-CC</sub>		PCIe Gen 4 (PLL BW of 2-4MHz, 2-5MHz, CDR = 10MHz)	0.3	0.37	0.44	0.5	ps (rms)	1, 2

#### Notes on PCle Filtered Phase Jitter Tables

<sup>&</sup>lt;sup>2</sup> Measured from differential waveform

<sup>&</sup>lt;sup>3</sup> Slew rate is measured through the Vswing voltage range centered around differential 0V. This results in a +/-150mV window around differential 0V

<sup>&</sup>lt;sup>4</sup> Matching applies to rising edge rate for Clock and falling edge rate for Clock#. It is measured using a +/-75mV window centered on the average cross point where Clock rising meets Clock# falling. The median cross point is used to calculate the voltage thresholds the oscilloscope is to use for the edge rate calculations.

<sup>&</sup>lt;sup>5</sup> Vcross is defined as voltage where Clock = Clock# measured on a component test board and only applies to the differential rising edge (i.e. Clock rising and Clock# falling).

<sup>&</sup>lt;sup>6</sup> The total variation of all Vcross measurements in any particular system. Note that this is a subset of Vcross\_min/max (Vcross absolute) allowed. The intent is to limit Vcross induced modulation by setting Δ-Vcross to be smaller than Vcross absolute.

<sup>&</sup>lt;sup>7</sup> At default SMBus settings.

<sup>&</sup>lt;sup>1</sup> Applies to all differential outputs, guaranteed by design and characterization.

<sup>&</sup>lt;sup>2</sup> Calculated from Intel-supplied Clock Jitter Tool, with spread on and off.

<sup>&</sup>lt;sup>3</sup> Sample size of at least 100K cycles. This figure extrapolates to 108ps pk-pk at 1M cycles for a BER of 1<sup>-12</sup>.



#### **Electrical Characteristics-REF**

TA = T<sub>COM</sub> or T<sub>IND</sub>; Supply Voltage per VDD of normal operation conditions, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	Notes
Long Accuracy	ppm	see Tperiod min-max values		0		ppm	1,2
Clock period	T <sub>period</sub>	25 MHz output nominal		40		ns	1,2
Rise/Fall Slew Rate	t <sub>rf1</sub>	$V_{OH} = VDD-0.45V, V_{OL} = 0.45V$	0.5	1.3	2.5	V/ns	1,3
Duty Cycle	d <sub>t1</sub>	$V_T = VDD/2 V$	45	49.1	55	%	1,4
Duty Cycle Distortion	d <sub>tcd</sub>	$V_T = VDD/2 V$	0	2	3	%	1,5
Jitter, cycle to cycle	t <sub>jcyc-cyc</sub>	$V_T = VDD/2 V$		19	250	ps	1,4
Noise floor	t <sub>jdBc1k</sub>	1kHz offset		-130	-105	dBc	1,4
Noise floor	t <sub>jdBc10k</sub>	10kHz offset to Nyquist		-140	-120	dBc	1,4
Jitter, phase	t <sub>jphREF</sub>	12kHz to 5MHz		0.63	1.5	ps (rms)	1,4

<sup>&</sup>lt;sup>1</sup>Guaranteed by design and characterization, not 100% tested in production.

### Clock Periods-Differential Outputs with Spread Spectrum Disabled

	Measurement Window									
	Center	1 Clock	1us	0.1s	0.1s	0.1s	1us	1 Clock		
SSC OFF	Freq. MHz	-c2c jitter	-SSC Sh	- ppm L	0 ppm Period Nominal	+ ppm L	+SSC Sh	+c2c jitter	Units	Notes
DIF	100.00	9.94900		9.99900	10.00000	10.00100		10.05100	ns	1,2

### Clock Periods-Differential Outputs with -0.5% Spread Spectrum Enabled

				Me	easurement W	indow				
	Center	1 Clock	1us	0.1s	0.1s	0.1s	1us	1 Clock	Units I	
	Freq. MHz	-c2c jitter	-SSC Sh	- ppm L	0 ppm Period Nominal	+ ppm L	+SSC Sh	+c2c jitter		Notes
DIF	99.75	9.94906	9.99906	10.02406	10.02506	10.02607	10.05107	10.10107	ns	1,2

<sup>&</sup>lt;sup>1</sup>Guaranteed by design and characterization, not 100% tested in production.

<sup>&</sup>lt;sup>2</sup> All Long Term Accuracy and Clock Period specifications are guaranteed assuming that REF is trimmed to 25.00 MHz

<sup>&</sup>lt;sup>3</sup> Typical value occurs when REF slew rate is set to default value

<sup>&</sup>lt;sup>4</sup> When driven by a crystal.

<sup>&</sup>lt;sup>5</sup> When driven by an external oscillator via the X1 pin. X2 should be floating in this case.

<sup>&</sup>lt;sup>2</sup> All Long Term Accuracy and Clock Period specifications are guaranteed assuming that REF is trimmed to 25.00 MHz



#### **General SMBus Serial Interface Information**

#### **How to Write**

- · Controller (host) sends a start bit
- · Controller (host) sends the write address
- IDT clock will acknowledge
- Controller (host) sends the beginning byte location = N
- IDT clock will acknowledge
- Controller (host) sends the byte count = X
- IDT clock will acknowledge
- Controller (host) starts sending Byte N through Byte N+X-1
- IDT clock will acknowledge each byte one at a time
- · Controller (host) sends a stop bit

	Index Bl	ock \	Write Operation
Controll	er (Host)		IDT (Slave/Receiver)
Т	starT bit		
Slave A	Address		
WR	WRite		
			ACK
Beginning	g Byte = N		
			ACK
Data Byte	Count = X		
			ACK
Beginnin	g Byte N		
			ACK
0		×	
0		X Byte	0
0		Ð	0
			0
Byte N	Byte N + X - 1		
			ACK
Р	stoP bit		

Note: Read/Write address is determined by SADR latch.

#### **How to Read**

- · Controller (host) will send a start bit
- Controller (host) sends the write address
- IDT clock will acknowledge
- Controller (host) sends the beginning byte location = N
- IDT clock will acknowledge
- · Controller (host) will send a separate start bit
- · Controller (host) sends the read address
- IDT clock will acknowledge
- IDT clock will send the data byte count = X
- IDT clock sends Byte N+X-1
- IDT clock sends Byte 0 through Byte X (if X<sub>(H)</sub> was written to Byte 8)
- Controller (host) will need to acknowledge each byte
- Controller (host) will send a not acknowledge bit
- · Controller (host) will send a stop bit

	Index Block F	Read O	peration
Cor	ntroller (Host)		IDT (Slave/Receiver)
Т	starT bit		
SI	ave Address		
WR	WRite		
			ACK
Begi	nning Byte = N		
			ACK
RT	Repeat starT		
SI	ave Address		
RD	ReaD		
			ACK
			Data Byte Count=X
	ACK		
			Beginning Byte N
	ACK		
		ę	0
	0	X Byte	0
	0	×	0
	0		
			Byte N + X - 1
N	Not acknowledge		
Р	stoP bit		



#### 2-OUTPUT VERY LOW POWER PCIE GEN 1-2-3-4 CLOCK GENERATOR

#### SMBus Table: Output Enable Register

Byte 0	Name	Control Function	Type	0	1	Default	
Bit 7	Reserved						
Bit 6	Reserved						
Bit 5	Reserved						
Bit 4	Reserved						
Bit 3		Reserved				1	
Bit 2	DIF OE1	Output Enable	RW	Low/Low	Enabled	1	
Bit 1	DIF OE0 Output Enable RW Low/Low Enabled						
Bit 0		Reserved				1	

#### SMBus Table: SS Readback and Vhigh Control Register

Byte 1	Name	Control Function	Type	0	1	Default
Bit 7	SSENRB1	SS Enable Readback Bit1	R	00' for SS_EN_tri =	0, '01' for SS_EN_tri	Latch
Bit 6	SSENRB1	SS Enable Readback Bit0	R	= 'M', '11 for S	S_EN_tri = '1'	Latch
Bit 5	SSEN_SWCNTRL	Enable SW control of SS	RW	SS control locked	Values in B1[4:3] control SS amount.	0
Bit 4	SSENSW1	SS Enable Software Ctl Bit1	RW <sup>1</sup>	00' = SS Off, '0'	1' = -0.25% SS,	0
Bit 3	SSENSW0	SS Enable Software Ctl Bit0	RW <sup>1</sup>	'10' = Reserved	, '11'= -0.5% SS	0
Bit 2		Reserved				1
Bit 1	AMPLITUDE 1	Controls Output Amplitude	RW	00 = 0.6V	01 = 0.7V	1
Bit 0	AMPLITUDE 0	Controls Catput Amplitude	RW	10= 0.8V	11 = 0.9V	0

<sup>1.</sup> B1[5] must be set to a 1 for these bits to have any effect on the part.

#### SMBus Table: DIF Slew Rate Control Register

Byte 2	Name	Control Function	Туре	0	1	Default	
Bit 7	Reserved						
Bit 6		Reserved					
Bit 5	Reserved						
Bit 4	Reserved						
Bit 3		Reserved				1	
Bit 2	SLEWRATESEL DIF1	Adjust Slew Rate of DIF1	RW	2.0V/ns	3.0V/ns	1	
Bit 1	SLEWRATESEL DIF0	Adjust Slew Rate of DIF0	RW	2.0V/ns	3.0V/ns	1	
Bit 0		Reserved				1	

#### SMBus Table: REF Control Register

Byte 3	Name	Control Function	Type	0	1	Default
Bit 7	REF	Slew Rate Control	RW	00 = 0.9 V/ns	01 =1.3V/ns	0
Bit 6	INLI	Siew Nate Control	RW	10 = 1.6V/ns	11 = 1.8V/ns	1
Bit 5	REF Power Down Function	Wake-on-Lan Enable for REF	RW	REF does not run in Power Down	REF runs in Power Down	0
Bit 4	REF OE	REF Output Enable	RW	Low	Enabled	1
Bit 3		Reserved				1
Bit 2		Reserved				1
Bit 1	Reserved					
Bit 0		Reserved				1

Byte 4 is reserved and reads back 'hFF'.

10



#### 2-OUTPUT VERY LOW POWER PCIE GEN 1-2-3-4 CLOCK GENERATOR

#### SMBus Table: Revision and Vendor ID Register

Byte 5	Name	Control Function	Туре	0	1	Default
Bit 7	RID3		R			0
Bit 6	RID2	Revision ID	R	Λ rov-	0	
Bit 5	RID1		R	A rev = 0000		0
Bit 4	RID0		R		0	
Bit 3	VID3		R		0	
Bit 2	VID2	VENDOR ID	R	0001 = IDT		0
Bit 1	VID1	VENDOR ID	R			0
Bit 0	VID0		R			1

SMBus Table: Device Type/Device ID

Byte 6	Name	Control Function	Туре	0	1	Default
Bit 7	Device Type1	Device Type	R	00 = FGV, 01 = DBV,		0
Bit 6	Device Type0	Device Type	R	10 = DMV, 1	0	
Bit 5	Device ID5		R			0
Bit 4	Device ID4	İ	R			0
Bit 3	Device ID3	Device ID	R	00010 bina	n, or 02 hev	0
Bit 2	Device ID2	Device iD	R	000 TO BITIAL	00010 binary or 02 hex	
Bit 1	Device ID1		R			1
Bit 0	Device ID0		R			0

#### SMBus Table: Byte Count Register

Byte 7	Name	Control Function	Type	0	1	Default
Bit 7		Reserved				0
Bit 6	Reserved					
Bit 5	Reserved					
Bit 4	BC4		RW			0
Bit 3	BC3		RW	Writing to this regist	ter will configure how	1
Bit 2	BC2	Byte Count Programming	RW	many bytes will be	read back, default is	0
Bit 1	BC1		RW	= 8 b	oytes.	0
Bit 0	BC0		RW			0

## Recommended Crystal Characteristics (3225 package)

PARAMETER	VALUE	UNITS	NOTES
Frequency	25	MHz	1
Resonance Mode	Fundamental	1	1
Frequency Tolerance @ 25°C	±20	PPM Max	1
Frequency Stability, ref @ 25°C Over Operating Temperature Range	±20	PPM Max	1
Temperature Range (commercial)	0~70	°C	1
Temperature Range (industrial)	-40~85	°C	2
Equivalent Series Resistance (ESR)	50	Ω Max	1
Shunt Capacitance (C <sub>O</sub> )	7	pF Max	1
Load Capacitance (C <sub>L</sub> )	8	pF Max	1
Drive Level	0.3	mW Max	1
Aging per year	±5	PPM Max	1

#### Notes:

- 1. FOX 603-25-150.
- 2. For I-temp, FOX 603-25-261.

11



### **Thermal Characteristics**

PARAMETER	SYMBOL	CONDITIONS	PKG	TYP VALUE	UNITS	NOTES
	θјς	Junction to Case	NLG20	62	°C/W	1
Thermal Resistance  θυ θυ	$\theta_{Jb}$	Junction to Base		5.4	°C/W	1
	$\theta_{JA0}$	Junction to Air, still air		50	°C/W	1
	$\theta_{JA1}$	Junction to Air, 1 m/s air flow	NLG24	43	°C/W	1
	$\theta_{JA3}$	Junction to Air, 3 m/s air flow	39	39	°C/W	1
	$\theta_{JA5}$	Junction to Air, 5 m/s air flow		38	°C/W	1

<sup>&</sup>lt;sup>1</sup>ePad soldered to board

### **Marking Diagrams**

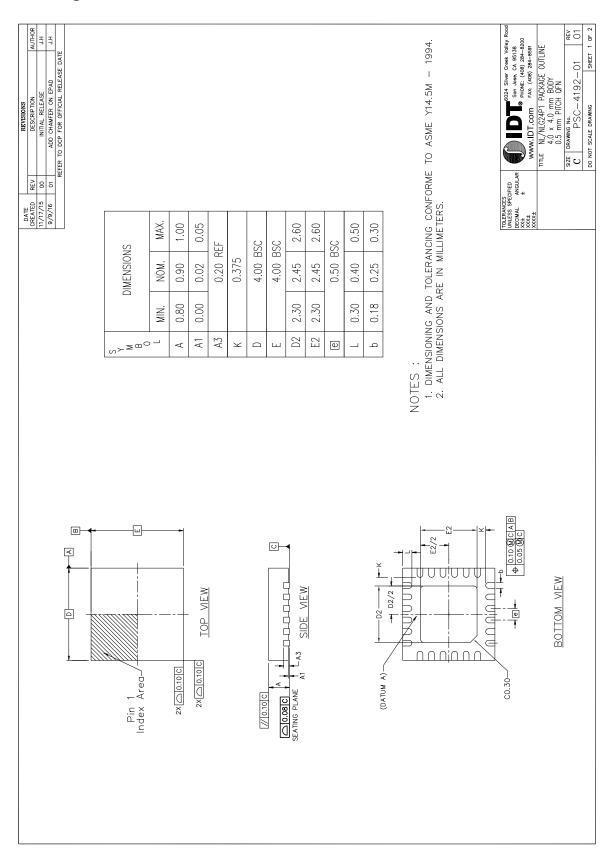




#### Notes:

- 1. 'LOT' is the lot number.
- 2. 'YYWW' is the last two digits of the year and week that the part was assembled.
- 3. 'L' denotes RoHS compliant package.
- 4. 'I' denotes industrial temperature grade.

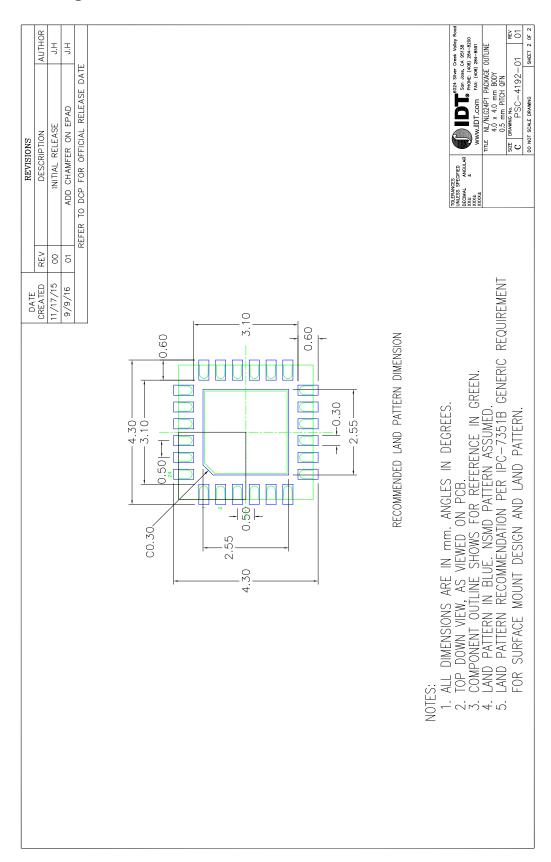
### **Package Outline and Dimensions (NLG24)**



#### 2-001P01

9FGV0231

### Package Outline and Dimensions (NLG24), cont.



9FGV0231

14



#### 2-OUTPUT VERY LOW POWER PCIE GEN 1-2-3-4 CLOCK GENERATOR

### **Ordering Information**

Part / Order Number	Shipping Packaging	Package	Temperature
9FGV0231AKLF	Trays	24-pin VFQFPN	0 to +70° C
9FGV0231AKLFT	Tape and Reel	24-pin VFQFPN	0 to +70° C
9FGV0231AKILF	Trays	24-pin VFQFPN	-40 to +85° C
9FGV0231AKILFT	Tape and Reel	24-pin VFQFPN	-40 to +85° C

<sup>&</sup>quot;LF" suffix to the part number are the Pb-Free configuration and are RoHS compliant.

### **Revision History**

Issue Date	Description
February 3, 2015	Updated IDDAOP and IDDOP min and max specs per latest characterization review.
October 18, 2016	Removed IDT crystal part number
	Updated front page Gendes to reflect the PCle Gen4 updates.(Refer to yellow Highlights)
June 19, 2017	Updated Electrical Characteristics - Filtered Phase Jitter Parameters - PCle Common
	Clocked (CC) Architectures and added PCle Gen4 Data
June 6, 2019	Updated Input Current minimum and maximum values from -200/200uA to -20/20uA.

<sup>&</sup>quot;A" is the device revision designator (will not correlate with the datasheet revision).



2-OUTPUT VERY LOW POWER PCIE GEN 1-2-3-4 CLOCK GENERATOR

**SYNTHESIZERS** 

#### IMPORTANT NOTICE AND DISCLAIMER

RENESAS ELECTRONICS CORPORATION AND ITS SUBSIDIARIES ("RENESAS") PROVIDES TECHNICAL SPECIFICATIONS AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS OR IMPLIED, INCLUDING, WITHOUT LIMITATION, ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE, OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for developers skilled in the art designing with Renesas products. You are solely responsible for (1) selecting the appropriate products for your application, (2) designing, validating, and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, or other requirements. These resources are subject to change without notice. Renesas grants you permission to use these resources only for development of an application that uses Renesas products. Other reproduction or use of these resources is strictly prohibited. No license is granted to any other Renesas intellectual property or to any third party intellectual property. Renesas disclaims responsibility for, and you will fully indemnify Renesas and its representatives against, any claims, damages, costs, losses, or liabilities arising out of your use of these resources. Renesas' products are provided only subject to Renesas' Terms and Conditions of Sale or other applicable terms agreed to in writing. No use of any Renesas resources expands or otherwise alters any applicable warranties or warranty disclaimers for these products.

(Rev.1.0 Mar 2020)

#### **Corporate Headquarters**

TOYOSU FORESIA, 3-2-24 Toyosu, Koto-ku, Tokyo 135-0061, Japan www.renesas.com

#### **Trademarks**

Renesas and the Renesas logo are trademarks of Renesas Electronics Corporation. All trademarks and registered trademarks are the property of their respective owners.

#### **Contact Information**

For further information on a product, technology, the most up-to-date version of a document, or your nearest sales office, please visit:

www.renesas.com/contact/

### **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Clock Generators & Support Products category:

Click to view products by Renesas manufacturer:

Other Similar products are found below:

CV183-2TPAG 950810CGLF 9DBV0741AKILF 9VRS4420DKLF CY25404ZXI226 CY25422SXI-004 MPC9893AE NB3H515001MNTXG PL602-20-K52TC ICS557GI-03LF PI6LC48P0101LIE 82P33814ANLG 840021AGLF ZL30244LFG7 PI6LC48C21LE
ZL30245LFG7 PI6LC48P0405LIE PI6LC48P03LE MAX24505EXG+ ZL30163GDG2 5L1503L-000NVGI8 ZL30156GGG2 ZL30673LFG7
MAX24188ETK2 ZL30152GGG2 5L1503-000NVGI8 PI6C557-01BZHIEX PI6LC48C21LIE CY2542QC002 5P35023-106NLGI
5X1503L-000NLGI8 ZL30121GGG2V2 ZL30282LDG1 ZL30102QDG1 ZL30159GGG2 DS1070K ZL30145GGG2 ZL30312GKG2
MAX24405EXG2 ZL30237GGG2 SY100EL34LZG 9FGV1002BQ506LTGI AD9518-4ABCPZ MX852BB0030 PI6LC4840ZHE AD95160BCPZ-REEL7 AD9574BCPZ-REEL7 PL602-21TC-R ZL30105QDG1 ZL30100QDG1